

Pb Free Plating Product

SF2004GA thru SF2008GA



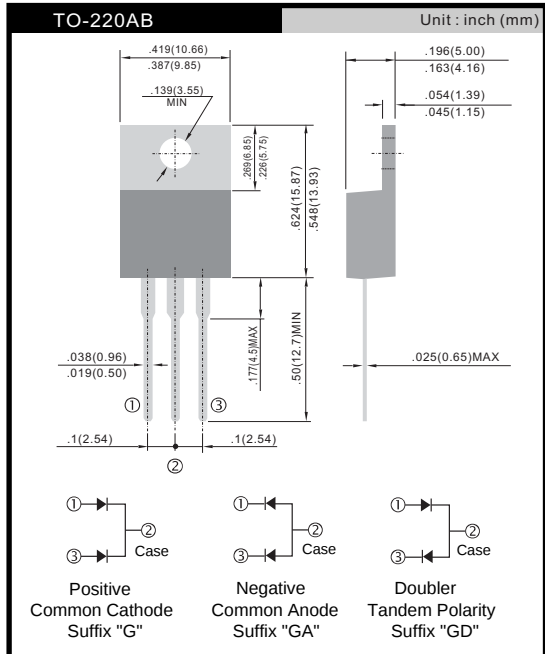
20.0 Ampere Dual Common Anode Super Fast Recovery Diode

Features

- ★ Fast switching for high efficiency
- ★ Low forward voltage drop
- ★ High current capability
- ★ Low reverse leakage current
- ★ High surge current capability

Mechanical Data

- ★ Case: TO-220AB Heatsink
- ★ Epoxy: UL 94V-0 rate flame retardant
- ★ Terminals: Solderable per MIL-STD-202 method 208
- ★ Polarity: As marked on body
- ★ Mounting position: Any
- ★ Weight: 2.24 gram approximately

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SYMBOL	SF2004G SF2004GA SF2004GD	SF2006G SF2006GA SF2006GD	SF2008G SF2008GA SF2008GD	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	200	400	600	V
Maximum RMS Voltage	VRMS	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=125°C	IF(AV)	20.0			A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	200	175		A
Maximum Instantaneous Forward Voltage @ 10.0 A	VF	0.98	1.30	1.70	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	10.0 250			uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35			nS
Typical junction Capacitance (Note 2)	CJ	120	70		pF
Operating Junction and Storage Temperature Range	TJ, TSTG	-55 to +150			°C

NOTES : (1) Reverse recovery test conditions I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

FIG.1 - FORWARD CURRENT DERATING CURVE

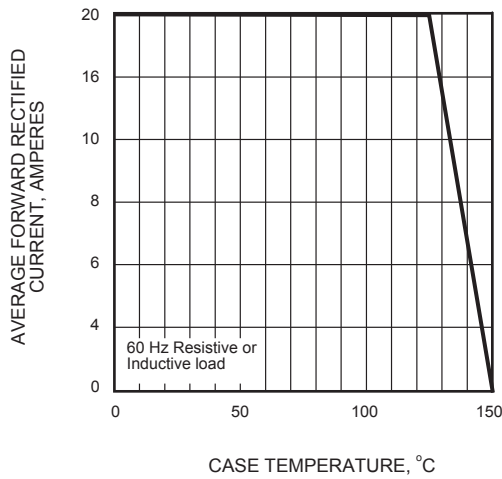


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

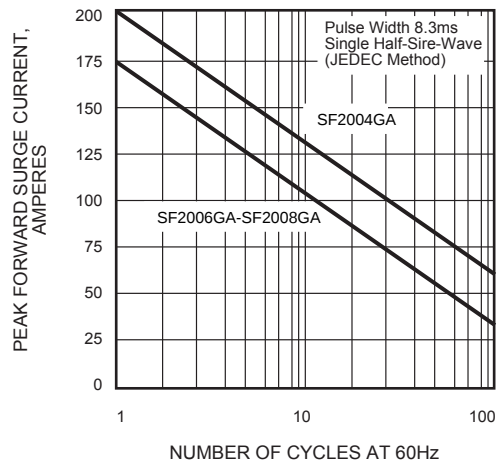


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

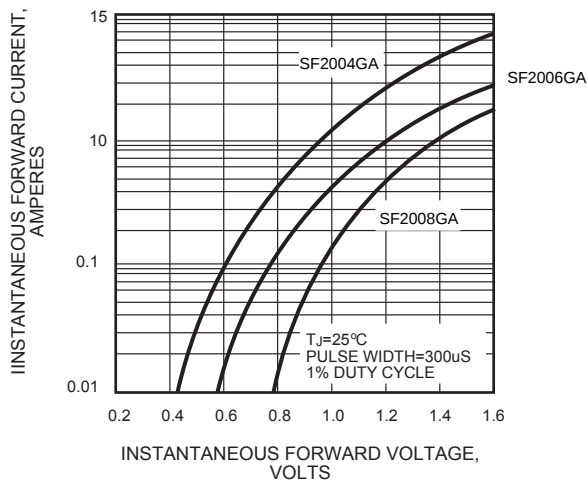


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

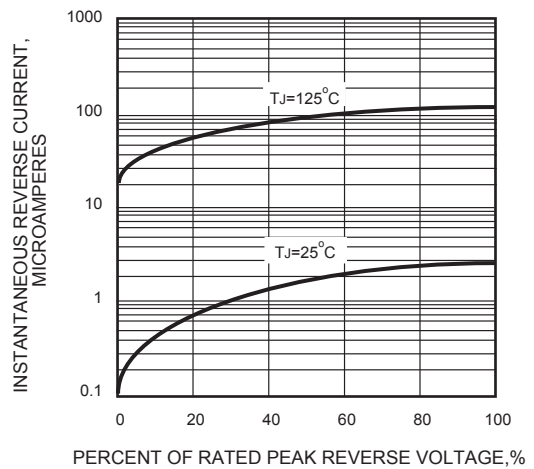


FIG.5 - TYPICAL JUNCTION CAPACITANCE

